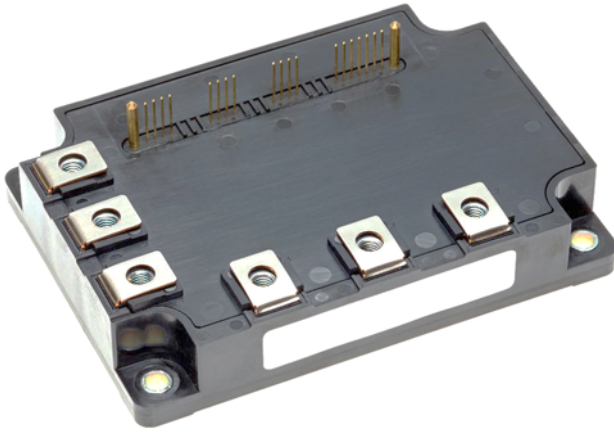


<Intelligent Power Modules>

# PM450CG1C065

FLAT-BASE TYPE  
INSULATED PACKAGE



## FEATURE

- a) Adopting Full-Gate CSTBT™ chip.
- b) The over-temperature protection which detects the chip surface temperature of CSTBT™ is adopted.
- c) Error output signal is available from each protection upper and lower arm of IPM.
- d) Outputting an error signal corresponding to the abnormal state (error mode identification)

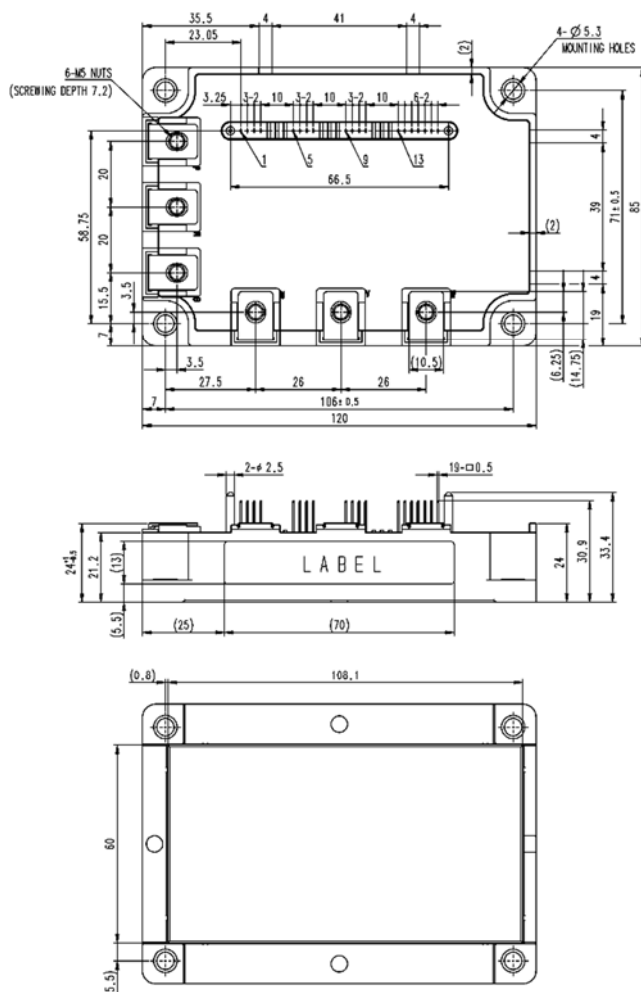
UL Recognized under UL1557, File No. E323585

This product is compliant with the Restriction of the Use of Certain Hazardous Substances in Electrical and Electronic Equipment (RoHS) directive 2011/65/EU.

## APPLICATION

General purpose inverter, servo drives and other motor controls

## PACKAGE OUTLINES



## Dimensions in mm

Tolerance otherwise specified

| Division of Dimension |        | Tolerance |
|-----------------------|--------|-----------|
| 0.5                   | to 3   | ±0.2      |
| over 3                | to 6   | ±0.3      |
| over 6                | to 30  | ±0.5      |
| over 30               | to 120 | ±0.8      |
| over 120              | to 400 | ±1.2      |

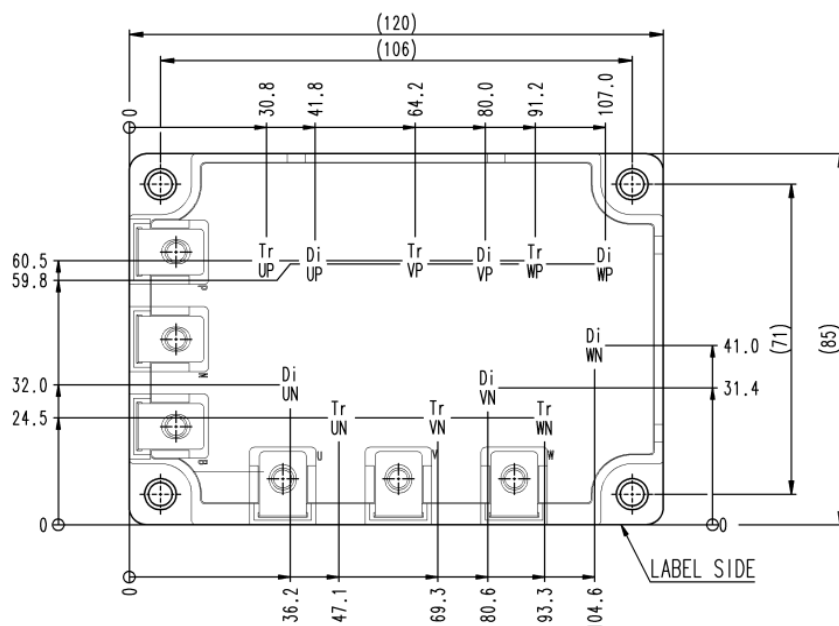
## TERMINAL CODE

- 1. V<sub>UPC</sub>
- 2. U<sub>FO</sub>
- 3. U<sub>P</sub>
- 4. V<sub>UP1</sub>
- 5. V<sub>VPC</sub>
- 6. V<sub>FO</sub>
- 7. V<sub>P</sub>
- 8. V<sub>VP1</sub>
- 9. V<sub>WPC</sub>
- 10. W<sub>FO</sub>
- 11. W<sub>P</sub>
- 12. V<sub>WP1</sub>
- 13. V<sub>NC</sub>
- 14. V<sub>N1</sub>
- 15. NC
- 16. U<sub>N</sub>
- 17. V<sub>N</sub>
- 18. W<sub>N</sub>
- 19. F<sub>O</sub>



**PM450CG1C065**HIGH POWER SWITCHING USE  
INSULATED TYPE**THERMAL RESISTANCE**

| Symbol         | Parameter                  | Conditions                                                             | Limits |      |      | Unit |
|----------------|----------------------------|------------------------------------------------------------------------|--------|------|------|------|
|                |                            |                                                                        | Min.   | Typ. | Max. |      |
| $R_{th(j-c)Q}$ | Thermal Resistance         | Junction to case, IGBT, per 1 element (Note1)                          | -      | -    | 0.09 | K/W  |
| $R_{th(j-c)D}$ |                            | Junction to case, FWD, per 1 element (Note1)                           | -      | -    | 0.14 |      |
| $R_{th(c-s)}$  | Contact Thermal Resistance | Case to heat sink, per 1 module,<br>Thermal grease applied (Note.1, 2) | -      | 8.4  | -    | K/kW |

Note1. If you use this value,  $R_{th(s-a)}$  should be measured just under the chips.Note2. Typical value is measured by using thermally conductive grease of  $\lambda=0.9W/(m \cdot K)$ ,  $D_{(c-s)}=50 \mu m$ .**CHIP LOCATION (Top view)**Dimension in mm, tolerance:  $\pm 1mm$ 

Tr\*\* : IGBT  
Di\*\* : FWD

**ELECTRICAL CHARACTERISTICS** ( $T_vj=25^\circ C$ , unless otherwise noted)**INVERTER PART**

| Symbol       | Parameter                            | Conditions                                                                                                                                                                                      |                                      |                                      |     | Limits |      |               | Unit |
|--------------|--------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------|--------------------------------------|-----|--------|------|---------------|------|
|              |                                      |                                                                                                                                                                                                 |                                      |                                      |     | Min.   | Typ. | Max.          |      |
| $V_{CEsat}$  | Collector-Emitter Saturation Voltage | $V_D=15\text{ V}$ , $I_C=450\text{ A}$                                                                                                                                                          | $T_{vj}=25\text{ }^{\circ}\text{C}$  | Terminal                             | -   | -      | 2.1  | V             |      |
|              |                                      |                                                                                                                                                                                                 |                                      | Chip                                 | -   | 1.25   | -    |               |      |
|              |                                      | $V_{CIN}=0\text{ V}$ , Pulsed, (Fig.1)                                                                                                                                                          | $T_{vj}=125\text{ }^{\circ}\text{C}$ | Terminal                             | -   | -      | 2.35 |               |      |
|              |                                      |                                                                                                                                                                                                 |                                      | Chip                                 | -   | 1.33   | -    |               |      |
| $V_{EC}$     | Emitter-Collector Voltage            | $V_D=15\text{ V}$ , $I_E=450\text{ A}$ ,                                                                                                                                                        | $T_{vj}=25\text{ }^{\circ}\text{C}$  | Terminal                             | -   | -      | 2.2  | V             |      |
|              |                                      |                                                                                                                                                                                                 |                                      | Chip                                 | -   | 1.40   | -    |               |      |
|              |                                      | $V_{CIN}=15\text{ V}$ , pulsed, (Fig.2)                                                                                                                                                         | $T_{vj}=125\text{ }^{\circ}\text{C}$ | Terminal                             | -   | -      | 2.3  |               |      |
|              |                                      |                                                                                                                                                                                                 |                                      | Chip                                 | -   | 1.45   | -    |               |      |
| $t_{on}$     | Switching Time                       | $V_D=15\text{ V}$ , $V_{CIN}=0\text{ V}\leftrightarrow 15\text{ V}$ ,<br>$V_{CC}=300\text{ V}$ , $I_C=450\text{ A}$ ,<br>$T_{vj}=125\text{ }^{\circ}\text{C}$ ,<br>Inductive Load<br>(Fig.3, 4) |                                      |                                      | 0.3 | 0.6    | 1.2  | $\mu\text{s}$ |      |
| $t_{rr}$     |                                      |                                                                                                                                                                                                 |                                      |                                      | -   | 0.2    | 0.65 |               |      |
| $t_{c(on)}$  |                                      |                                                                                                                                                                                                 |                                      |                                      | -   | 0.2    | 0.75 |               |      |
| $t_{off}$    |                                      |                                                                                                                                                                                                 |                                      |                                      | -   | 1.3    | 2.3  |               |      |
| $t_{c(off)}$ |                                      |                                                                                                                                                                                                 |                                      |                                      | -   | 0.2    | 0.4  |               |      |
| $I_{CES}$    | Collector-Emitter Cut-off Current    | $V_{CE}=V_{CES}$ , $V_D=15\text{ V}$ ,<br>$V_{CIN}=15\text{ V}$ (Fig.5)                                                                                                                         |                                      | $T_{vj}=25\text{ }^{\circ}\text{C}$  | -   | -      | 1    | mA            |      |
|              |                                      |                                                                                                                                                                                                 |                                      | $T_{vj}=125\text{ }^{\circ}\text{C}$ | -   | -      | 10   |               |      |

**PM450CG1C065**HIGH POWER SWITCHING USE  
INSULATED TYPE**ELECTRICAL CHARACTERISTICS** (Tvj = 25°C, unless otherwise noted)**CONTROL PART**

| Symbol               | Parameter                        | Conditions                                                                                                                                                                                     | Limits      |      |      | Unit |
|----------------------|----------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------|------|------|------|
|                      |                                  |                                                                                                                                                                                                | Min.        | Typ. | Max. |      |
| I <sub>D</sub>       | Circuit Current                  | V <sub>D</sub> =15 V, V <sub>CIN</sub> =15 V                                                                                                                                                   | -           | 4    | 6    | mA   |
|                      |                                  |                                                                                                                                                                                                |             | 12   | 18   |      |
|                      |                                  | V <sub>D</sub> =15 V, V <sub>CIN</sub> =0 V ↔ 15 V, V <sub>CC</sub> =400 V<br>I <sub>C</sub> =0A, Tvj=125 °C, f <sub>C</sub> ≤20kHz                                                            | -           | 52   | 63   |      |
|                      |                                  |                                                                                                                                                                                                |             | 157  | 188  |      |
| V <sub>th(ON)</sub>  | Input ON Threshold Voltage       | Applied between:<br>U <sub>P</sub> -V <sub>UPC</sub> , V <sub>P</sub> -V <sub>VPC</sub> , W <sub>P</sub> -V <sub>WPC</sub> , U <sub>N</sub> , V <sub>N</sub> , W <sub>N</sub> -V <sub>NC</sub> | 1.2         | 1.5  | 1.8  | V    |
| V <sub>th(OFF)</sub> | Input OFF Threshold Voltage      |                                                                                                                                                                                                | 1.7         | 2.0  | 2.3  |      |
| SC                   | Short Circuit Trip Level         | -20≤Tvj≤125 °C, V <sub>D</sub> =15 V (Fig.3, 6)                                                                                                                                                | 675         | -    | -    | A    |
| t <sub>d(SC)</sub>   | Short Circuit Current Delay Time | V <sub>D</sub> =15 V, Tvj=125 °C (Fig.3, 6)                                                                                                                                                    | -           | 2.0  | -    | μs   |
| OT                   | Over Temperature Protection      | Detect temperature of IGBT chip surface                                                                                                                                                        | Trip level  | 150  | -    | °C   |
| OT <sub>(hys)</sub>  |                                  |                                                                                                                                                                                                | Hysteresis  | -    | 20   |      |
| UV <sub>t</sub>      | Supply Circuit                   | -                                                                                                                                                                                              | Trip level  | 11.0 | 12.0 | V    |
| UV <sub>r</sub>      | Under-Voltage Protection         |                                                                                                                                                                                                | Reset level | -    | 12.5 |      |
| I <sub>FO(H)</sub>   | Fault Output Current             | V <sub>D</sub> =15 V, V <sub>FO</sub> =15 V (Note3)                                                                                                                                            | -           | -    | 0.01 | mA   |
| I <sub>FO(L)</sub>   |                                  |                                                                                                                                                                                                | -           | 10   | 15   |      |
| t <sub>FO</sub>      | Fault Output Pulse Width         | V <sub>D</sub> =15 V (Note3)                                                                                                                                                                   | OT          | -    | 8.0  | ms   |
|                      |                                  |                                                                                                                                                                                                | UV          | -    | 4.0  |      |
|                      |                                  |                                                                                                                                                                                                | SC          | -    | 2.0  |      |

Note3. Fault output is given only when the internal SC, OT &amp; UV protections schemes of either upper or lower arm device operate to protect it.

**MECHANICAL RATINGS AND CHARACTERISTICS**

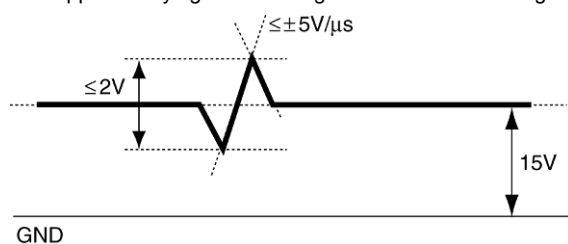
| Symbol         | Parameter       | Conditions                    | Limits |      |      | Unit |
|----------------|-----------------|-------------------------------|--------|------|------|------|
|                |                 |                               | Min.   | Typ. | Max. |      |
| M <sub>s</sub> | Mounting Torque | Mounting part screw : M5      | 2.5    | 3.0  | 3.5  | N•m  |
| M <sub>t</sub> | Mounting Torque | Main terminal part screw : M5 | 2.5    | 3.0  | 3.5  |      |
| m              | mass            | -                             | -      | 425  | -    | g    |

**RECOMMENDED CONDITIONS FOR USE**

| Symbol                | Parameter                       | Conditions                                                                                                                                                                                      | Recommended value | Unit |
|-----------------------|---------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------|------|
| V <sub>CC</sub>       | Supply Voltage                  | Applied across P-N terminals                                                                                                                                                                    | ≤ 400             | V    |
| V <sub>D</sub>        | Control Supply Voltage          | Applied between :<br>V <sub>UP1</sub> -V <sub>UPC</sub> , V <sub>VP1</sub> -V <sub>VPC</sub> , V <sub>WP1</sub> -V <sub>WPC</sub> , V <sub>N1</sub> -V <sub>NC</sub> (Note4)                    | 15.0±1.5          | V    |
| V <sub>CIN(ON)</sub>  | Input ON Voltage                | Applied between :<br>U <sub>P</sub> -V <sub>UPC</sub> , V <sub>P</sub> -V <sub>VPC</sub> , W <sub>P</sub> -V <sub>WPC</sub> , U <sub>N</sub> , V <sub>N</sub> , W <sub>N</sub> -V <sub>NC</sub> | ≤ 0.8             | V    |
| V <sub>CIN(OFF)</sub> | Input OFF Voltage               |                                                                                                                                                                                                 | ≥ 9.0             |      |
| f <sub>PWM</sub>      | PWM Input Frequency             | Using Application Circuit of Fig. 8                                                                                                                                                             | ≤ 20              | kHz  |
| t <sub>dead</sub>     | Arm Shoot-through Blocking Time | For IPM's each input signals (Fig.7)                                                                                                                                                            | ≥ 2.0             | μs   |

This product is compliant with the Restriction of the Use of Certain Hazardous Substances in Electrical and Electronic Equipment (RoHS) directive 2011/65/EU.

Note4. With ripple satisfying the following conditions: dv/dt swing ≤ ±5 V/μs, Variation ≤ 2 V peak to peak



**PM450CG1C065**HIGH POWER SWITCHING USE  
INSULATED TYPE**PRECAUTIONS FOR TESTING**

1. Before applying any control supply voltage ( $V_D$ ), the input terminals should be pulled up by resistors, etc. to their corresponding supply voltage and each input signal should be kept off state.

After this, the specified ON and OFF level setting for each input signal should be done.

2. When performing "SC" tests, the turn-off surge voltage spike at the corresponding protection operation should not be allowed to rise above  $V_{CES}$  rating of the device.

(These test should not be done by using a curve tracer or its equivalent.)

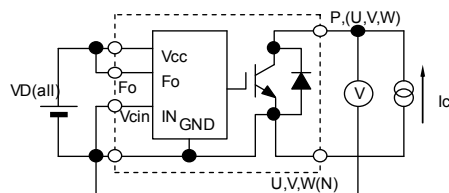
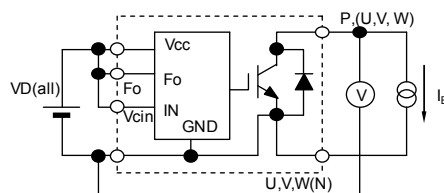
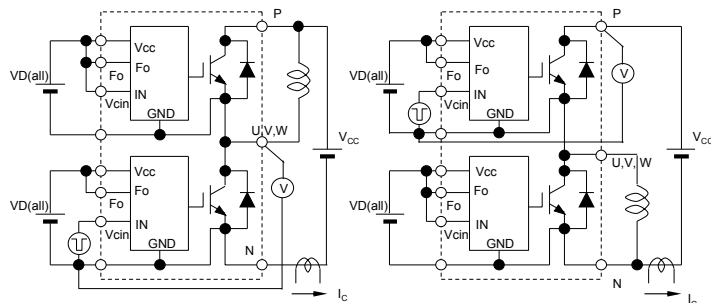
Fig.1  $V_{CESat}$  TestFig.2  $V_{EC}$  Test

Fig.3 Switching time and SC test circuit

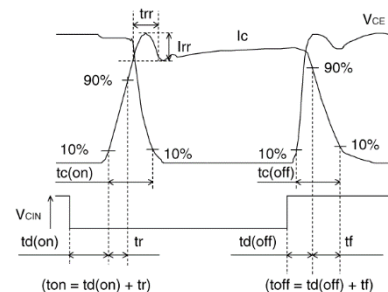


Fig.4 Switching time test waveform

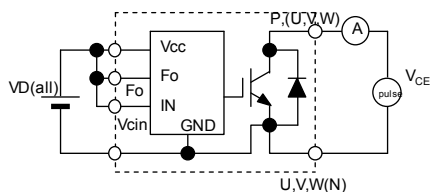
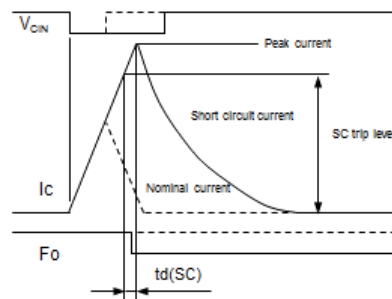
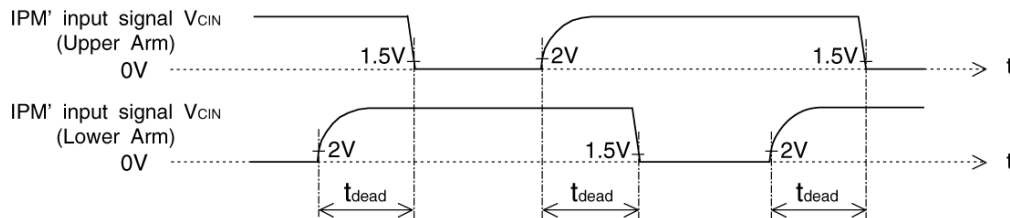
Fig.5  $I_{CES}$  Test

Fig.6 SC test waveform



1.5V: Input on threshold voltage  $V_{th(on)}$  typical value, 2V: Input off threshold voltage  $V_{th(off)}$  typical value

Fig. 7 Dead time measurement point example

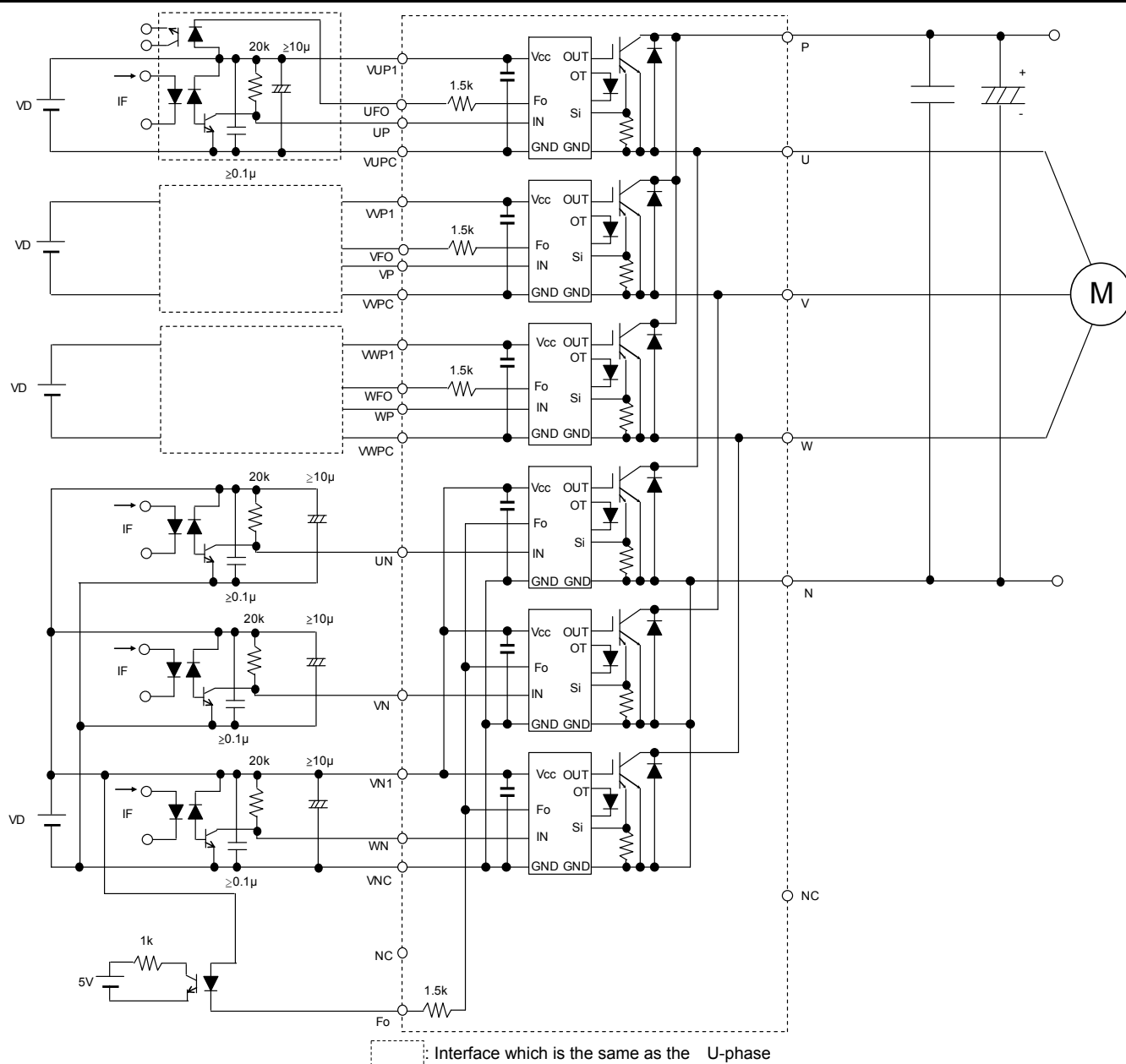
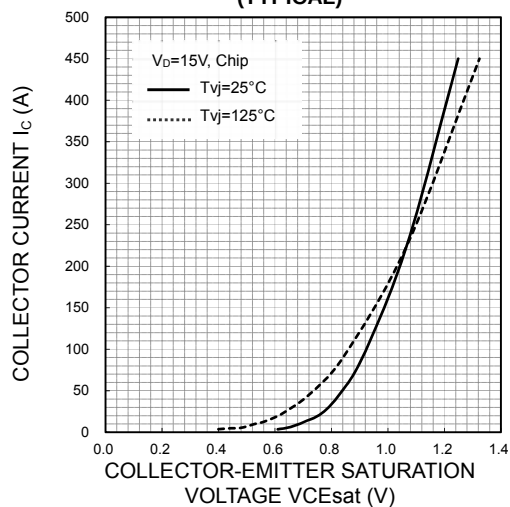
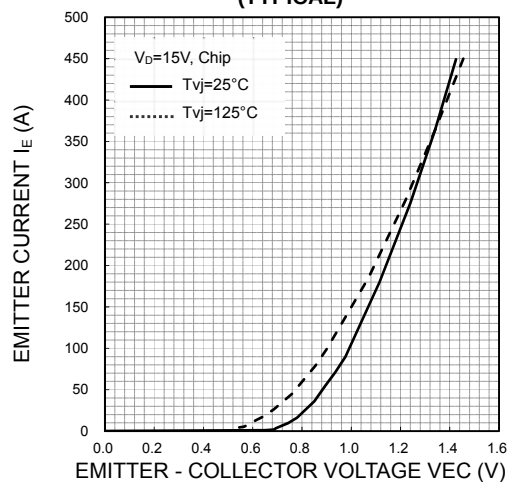
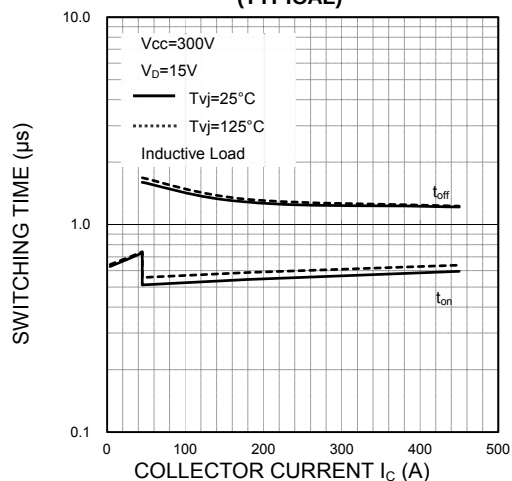
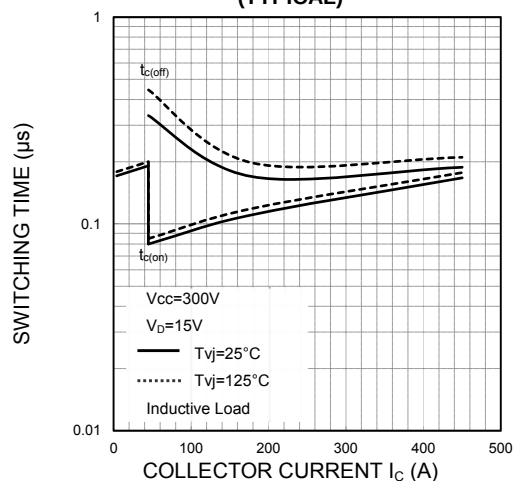
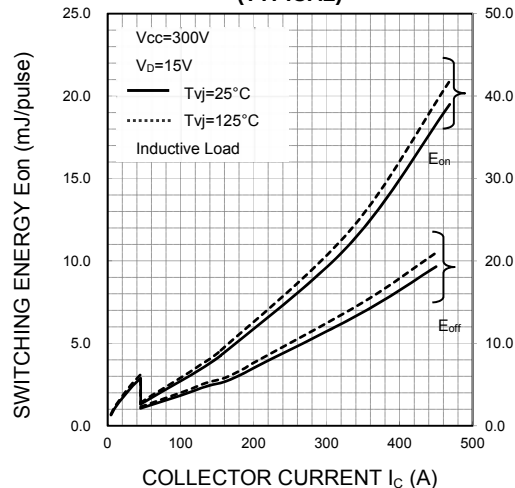
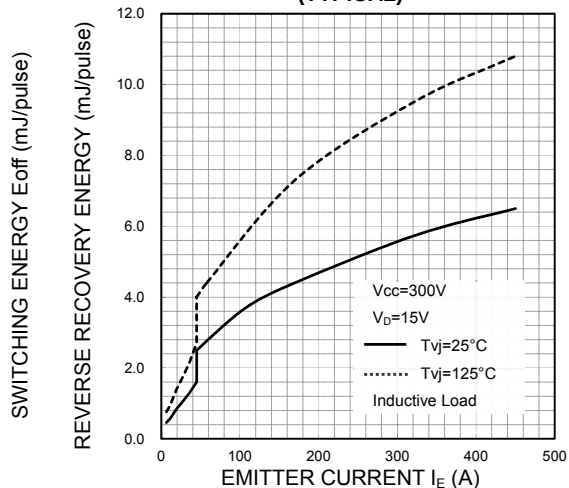
**PM450CG1C065**HIGH POWER SWITCHING USE  
INSULATED TYPE

Fig. 8 Application Example Circuit

**NOTES FOR STABLE AND SAFE OPERATION ;**

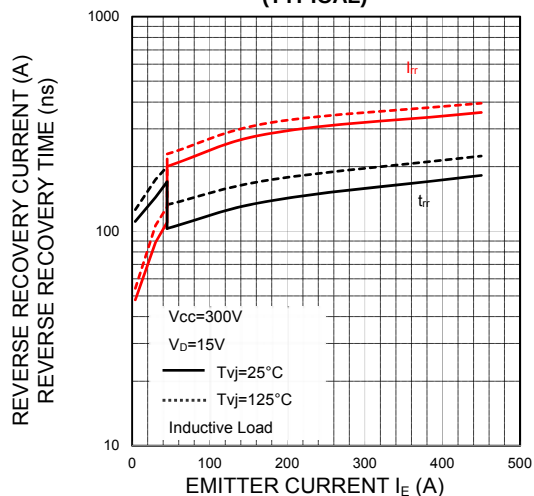
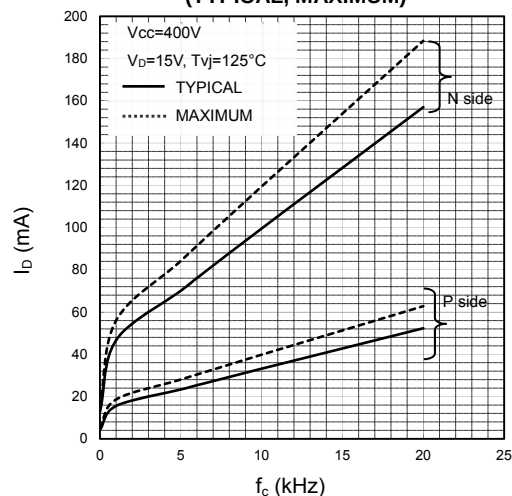
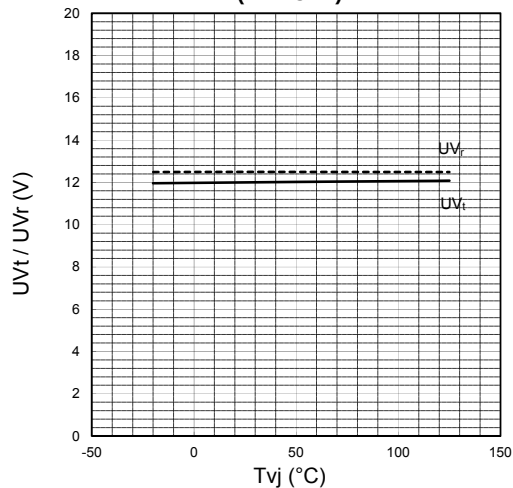
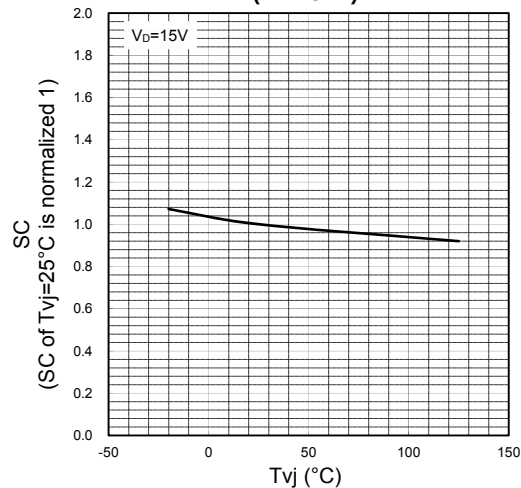
- Design the PCB pattern to minimize wiring length between opto-coupler and IPM's input terminal, and also to minimize the stray capacity between the input and output wirings of opto-coupler.
- Connect low impedance capacitor between the Vcc and GND terminal of each fast switching opto-coupler.
- Fast switching opto-couplers:  $t_{PLH}, t_{PHL} \leq 0.8\mu s$ , Use High CMR type.
- Slow switching opto-coupler: CTR > 100%
- Use 4 isolated control power supplies ( $V_D$ ). Also, care should be taken to minimize the instantaneous voltage charge of the power supply.
- Make inductance of DC bus line as small as possible, and minimize surge voltage using snubber capacitor between P and N terminal.

**PERFORMANCE CURVES****COLLECTOR-EMITTER SATURATION VOLTAGE (VS.  $I_C$ ) CHARACTERISTICS (TYPICAL)****FREE WHEELING DIODE FORWARD CHARACTERISTICS (TYPICAL)****SWITCHING TIME ( $t_{on}$ ,  $t_{off}$ ) CHARACTERISTICS (TYPICAL)****SWITCHING TIME ( $t_{c(on)}$ ,  $t_{c(off)}$ ) CHARACTERISTICS (TYPICAL)****SWITCHING ENERGY CHARACTERISTICS (TYPICAL)****FREE WHEELING DIODE REVERSE RECOVERY ENERGY CHARACTERISTICS (TYPICAL)**

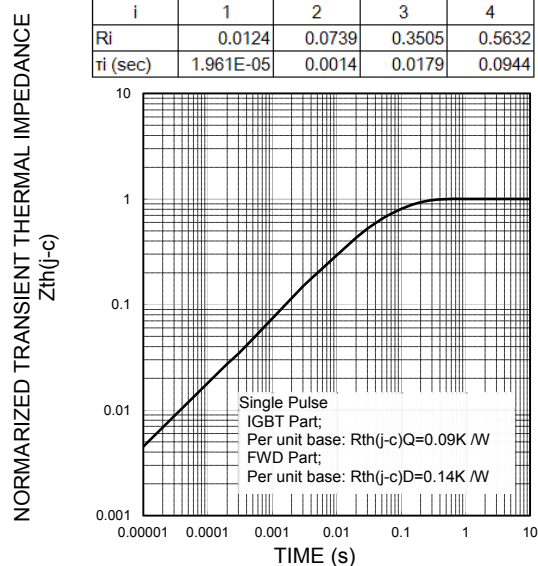
**PM450CG1C065**

HIGH POWER SWITCHING USE

INSULATED TYPE

**FREE WHEELING DIODE REVERSE RECOVERY CHARACTERISTICS (TYPICAL)** **$I_D$  VS.  $f_c$  CHARACTERISTICS (TYPICAL, MAXIMUM)****UV TRIP LEVEL VS.  $T_{vj}$  CHARACTERISTICS (TYPICAL)****SC TRIP LEVEL VS.  $T_{vj}$  CHARACTERISTICS (TYPICAL)****TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (TYPICAL)**

| i              | 1         | 2      | 3      | 4      |
|----------------|-----------|--------|--------|--------|
| $R_i$          | 0.0124    | 0.0739 | 0.3505 | 0.5632 |
| $\tau_i$ (sec) | 1.961E-05 | 0.0014 | 0.0179 | 0.0944 |



**Keep safety first in your circuit designs!**

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